



**MICROCIRCUIT DATA SHEET**

**MJLM124-X REV 1B1**

Original Creation Date: 07/19/95  
 Last Update Date: 03/28/02  
 Last Major Revision Date: 03/16/00

**QUAD OPERATIONAL AMPLIFIER, SINGLE SUPPLY, LOW POWER**

**General Description**

The LM124 consists of four independent, high gain, internally frequency compensated operational amplifiers which were designed specifically to operate from a single power supply over a wide range of voltages. Operation from split power supplies is also possible and the low power supply current drain is independent of the magnitude of the power supply voltage.

Application areas include transducer amplifiers, DC gain blocks and all the conventional op amp circuits which now can be more easily implemented in single power supply systems. For example, the LM124 can be directly operated off of the standard +5 VDC power supply voltage which is used in digital systems and will easily provide the required interface electronics without requiring the additional  $\pm 15$  VDC power supplies.

**Industry Part Number**

LM124

**Prime Die**

LM124

**NS Part Numbers**

JL124BCA  
 JL124BDA  
 JL124BZA  
 JL124SCA  
 JL124SDA

**Controlling Document**

38510/11005,AMEND.2 CIR.F REV B

**Processing**

MIL-STD-883, Method 5004

**Quality Conformance Inspection**

MIL-STD-883, Method 5005

| Subgrp | Description         | Temp ( °C) |
|--------|---------------------|------------|
| 1      | Static tests at     | +25        |
| 2      | Static tests at     | +125       |
| 3      | Static tests at     | -55        |
| 4      | Dynamic tests at    | +25        |
| 5      | Dynamic tests at    | +125       |
| 6      | Dynamic tests at    | -55        |
| 7      | Functional tests at | +25        |
| 8A     | Functional tests at | +125       |
| 8B     | Functional tests at | -55        |
| 9      | Switching tests at  | +25        |
| 10     | Switching tests at  | +125       |
| 11     | Switching tests at  | -55        |

**(Absolute Maximum Ratings)**

(Note 1)

|                              |                      |                     |
|------------------------------|----------------------|---------------------|
| Power Dissipation            |                      |                     |
| CERDIP                       |                      | 400mW               |
| CERPACK                      |                      | 350mW               |
| CERAMIC SOIC                 |                      | 350mW               |
| Supply Voltage               |                      |                     |
| V+                           |                      | 36Vdc or ±18Vdc     |
| Input Voltage Differential   |                      |                     |
|                              |                      | 30Vdc               |
| Input Voltage                |                      |                     |
|                              |                      | -0.03Vdc to +32Vdc  |
| Input Current                |                      |                     |
| (Note 3)                     |                      |                     |
| (Vin < -0.3 Vdc)             |                      | 10 to 0.1mA         |
| Output Short-Circuit to GND  |                      |                     |
| (Note 4)                     |                      |                     |
| (One Amplifier)              |                      |                     |
| V+ ≤ 15Vdc and TA = 25 C     |                      | Continuous          |
| Operating Temperature Range  |                      |                     |
|                              |                      | -55 C ≤ Ta ≤ +125 C |
| Maximum Junction Temperature |                      |                     |
| (Note 2)                     |                      | 175 C               |
| Storage Temperature Range    |                      |                     |
|                              |                      | -65 C ≤ Ta ≤ +150 C |
| Lead Temperature             |                      |                     |
| (Soldering, 10 seconds)      |                      | 260 C               |
| Thermal Resistance           |                      |                     |
| ThetaJA                      |                      |                     |
| CERDIP                       | (Still Air)          | 120 C/W             |
|                              | (500LF/Min Air Flow) | 51 C/W              |
| CERPACK                      | (Still Air)          | 140 C/W             |
|                              | (500LF/Min Air Flow) | 116 C/W             |
| CERAMIC SOIC                 | (Still Air)          | 140 C/W             |
|                              | (500LF/Min Air Flow) | 116 C/W             |
| ThetaJC                      |                      |                     |
| CERDIP                       |                      | 35 C/W              |
| CERPACK                      |                      | 60 C/W              |
| CERAMIC SOIC                 |                      | 60 C/W              |
| Package Weight               |                      |                     |
| CERDIP                       |                      | TBD                 |
| CERPACK                      |                      | 460mg               |
| CERAMIC SOIC                 |                      | 410mg               |
| ESD Tolerance                |                      |                     |
| (Note 5)                     |                      | 250 V               |

Note 1: Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is functional, but do not guarantee specific performance limits. For guaranteed specifications and test conditions, see the Electrical Characteristics. The guaranteed specifications apply only for the test conditions listed. Some performance characteristics may degrade when the device is not operated under the listed test conditions.

Note 2: The maximum power dissipation must be derated at elevated temperatures and is dictated by Tjmax (maximum junction temperature), ThetaJA (package junction to ambient thermal resistance), and TA (ambient temperature). The maximum allowable power dissipation at any temperature is Pdmax = (Tjmax - TA) / ThetaJA or the number given in the Absolute Maximum Ratings, whichever is lower.

**(Continued)**

- Note 3: This input current will only exist when the voltage at any of the input leads is driven negative. It is due to the collector-base junction of the input PNP transistors becoming forward biased and thereby acting as input diode clamps. In addition to this diode action, there is also lateral NPN parasitic transistor action on the IC chip. This transistor action can cause the output voltages of the op amps to go to the V+ voltage level (or to ground for a large overdrive) for the time duration that an input is driven negative. This is not destructive and normal output states will re-establish when the input voltage, which was negative, again returns to a value greater than -0.3 VDC (at 25 C).
- Note 4: Short circuits from the output to V+ can cause excessive heating and eventual destruction. When considering short circuits to ground, the maximum output current is approximately 40 mA independent of the magnitude of V+. At values of supply voltage in excess of +15 VDC, continuous short-circuits can exceed the power dissipation ratings and cause eventual destruction. Destructive dissipation can result from simultaneous shorts on all amplifiers.
- Note 5: Human body model, 1.5K ohms in series with 100 pF.

## Electrical Characteristics

### DC PARAMETERS

| SYMBOL                                | PARAMETER            | CONDITIONS                            | NOTES                | PIN-NAME                           | MIN  | MAX  | UNIT | SUB-GROUPS |    |      |
|---------------------------------------|----------------------|---------------------------------------|----------------------|------------------------------------|------|------|------|------------|----|------|
| Vio                                   | Input Offset Voltage | Vcc+ = 30V, Vcc- = Gnd, Vcm = -15V    |                      |                                    | -5   | 5    | mV   | 1          |    |      |
|                                       |                      |                                       |                      |                                    | -7   | 7    | mV   | 2, 3       |    |      |
|                                       |                      | Vcc+ = 2V, Vcc- = -28V, Vcm = 13V     |                      |                                    | -5   | 5    | mV   | 1          |    |      |
|                                       |                      |                                       |                      |                                    | -7   | 7    | mV   | 2, 3       |    |      |
|                                       |                      | Vcc+ = 5V, Vcc- = Gnd, Vcm = -1.4V    |                      |                                    | -5   | 5    | mV   | 1          |    |      |
|                                       |                      |                                       |                      |                                    | -7   | 7    | mV   | 2, 3       |    |      |
|                                       |                      | Vcc+ = 2.5V, Vcc- = -2.5V, Vcm = 1.1V |                      |                                    | -5   | 5    | mV   | 1          |    |      |
|                                       |                      |                                       |                      |                                    | -7   | 7    | mV   | 2, 3       |    |      |
|                                       |                      | Iio                                   | Input Offset Current | Vcc+ = 30V, Vcc- = Gnd, Vcm = -15V |      |      | -30  | 30         | nA | 1, 2 |
|                                       |                      |                                       |                      |                                    |      |      | -75  | 75         | nA | 3    |
| Vcc+ = 2V, Vcc- = -28V, Vcm = 13V     |                      |                                       |                      |                                    | -30  | 30   | nA   | 1, 2       |    |      |
|                                       |                      |                                       |                      |                                    | -75  | 75   | nA   | 3          |    |      |
| Vcc+ = 5V, Vcc- = Gnd, Vcm = -1.4V    |                      |                                       |                      |                                    | -30  | 30   | nA   | 1, 2       |    |      |
|                                       |                      |                                       |                      |                                    | -75  | 75   | nA   | 3          |    |      |
| Vcc+ = 2.5V, Vcc- = -2.5V, Vcm = 1.1V |                      |                                       |                      |                                    | -30  | 30   | nA   | 1, 2       |    |      |
|                                       |                      |                                       |                      |                                    | -75  | 75   | nA   | 3          |    |      |
| +Iib                                  | Input Bias Current   |                                       |                      | Vcc+ = 30V, Vcc- = Gnd, Vcm = -15V |      |      | -150 | +0.1       | nA | 1, 2 |
|                                       |                      |                                       |                      |                                    |      |      | -300 | +0.1       | nA | 3    |
|                                       |                      | Vcc+ = 2V, Vcc- = -28V, Vcm = 13V     |                      |                                    | -150 | +0.1 | nA   | 1, 2       |    |      |
|                                       |                      |                                       |                      |                                    | -300 | +0.1 | nA   | 3          |    |      |
|                                       |                      | Vcc+ = 5V, Vcc- = Gnd, Vcm = -1.4V    |                      |                                    | -150 | +0.1 | nA   | 1, 2       |    |      |
|                                       |                      |                                       |                      |                                    | -300 | +0.1 | nA   | 3          |    |      |
|                                       |                      | Vcc+ = 2.5V, Vcc- = -2.5V, Vcm = 1.1V |                      |                                    | -150 | +0.1 | nA   | 1, 2       |    |      |
|                                       |                      |                                       |                      |                                    | -300 | +0.1 | nA   | 3          |    |      |

## Electrical Characteristics

## DC PARAMETERS (Continued)

| SYMBOL                         | PARAMETER                                    | CONDITIONS  | NOTES                        | PIN-NAME   | MIN  | MAX  | UNIT  | SUB-GROUPS |      |         |
|--------------------------------|--|---|------------------------------|--|------|------|-------|------------|------|---------|
| -I <sub>ib</sub>               | Input Bias Current                           | V <sub>cc+</sub> = 30V, V <sub>cc-</sub> = Gnd, V <sub>cm</sub> = -15V                        |                              |  | -150 | +0.1 | nA    | 1, 2       |      |         |
|                                |  |   |                              |  | -300 | +0.1 | nA    | 3          |      |         |
|                                |  | V <sub>cc+</sub> = 2V, V <sub>cc-</sub> = -28V, V <sub>cm</sub> = 13V                         |                              |  | -150 | +0.1 | nA    | 1, 2       |      |         |
|                                |  |   |                              |  | -300 | +0.1 | nA    | 3          |      |         |
|                                |  | V <sub>cc+</sub> = 5V, V <sub>cc-</sub> = Gnd, V <sub>cm</sub> = -1.4V                        |                              |  | -150 | +0.1 | nA    | 1, 2       |      |         |
|                                |  |   |                              |  | -300 | +0.1 | nA    | 3          |      |         |
|                                |  | V <sub>cc+</sub> = 2.5V, V <sub>cc-</sub> = -2.5V, V <sub>cm</sub> = 1.1V                     |                              |  | -150 | +0.1 | nA    | 1, 2       |      |         |
|                                |  |   |                              |  | -300 | +0.1 | nA    | 3          |      |         |
|                                |  | +PSRR   | Power Supply Rejection Ratio | V <sub>cc-</sub> = Gnd, V <sub>cm</sub> = -1.4V,<br>5V ≤ V <sub>cc</sub> ≤ 30V |      |      | -100  | 100        | uV/V | 1, 2, 3 |
|                                |  | CMRR  | Common Mode Rejection Ratio  |  |      |      | 76    |            | dB   | 1, 2, 3 |
| I <sub>os+</sub>               | Output Short Circuit Current                 | V <sub>cc+</sub> = 30V, V <sub>cc-</sub> = Gnd, V <sub>o</sub> = +25V                         |                              |  | -70  |      | mA    | 1, 2, 3    |      |         |
| I <sub>cc</sub>                | Power Supply Current                         | V <sub>cc+</sub> = 30V, V <sub>cc-</sub> = Gnd  |                              |  |      | 3    | mA    | 1, 2       |      |         |
|                                |  |   |                              |  |      | 4    | mA    | 3          |      |         |
| Delta V <sub>io</sub> /Delta T | Input Offset Voltage Temperature Sensitivity | +25 C ≤ TA ≤ +125 C, +V <sub>cc</sub> = 5V,<br>-V <sub>cc</sub> = 0V, V <sub>cm</sub> = -1.4V | 3                            |  | -30  | 30   | uV/°C | 2          |      |         |
|                                |  | -55 C ≤ TA ≤ +25 C, +V <sub>cc</sub> = 5V,<br>-V <sub>cc</sub> = 0V, V <sub>cm</sub> = -1.4V  | 3                            |  | -30  | 30   | uV/°C | 3          |      |         |
| Delta I <sub>io</sub> /Delta T | Input Offset Current Temperature Sensitivity | +25 C ≤ TA ≤ +125 C, +V <sub>cc</sub> = 5V,<br>-V <sub>cc</sub> = 0V, V <sub>cm</sub> = -1.4V | 3                            |  | -400 | 400  | pA/°C | 2          |      |         |
|                                |  | -55 C ≤ TA ≤ +25 C, +V <sub>cc</sub> = 5V,<br>-V <sub>cc</sub> = 0V, V <sub>cm</sub> = -1.4V  | 3                            |  | -700 | 700  | pA/°C | 3          |      |         |
| V <sub>ol</sub>                | Logical "0" Output Voltage                   | V <sub>cc+</sub> = 30V, V <sub>cc-</sub> = Gnd, R <sub>l</sub> = 10K Ohms                     |                              |  |      | 35   | mV    | 4, 5, 6    |      |         |
|                                |  | V <sub>cc+</sub> = 30V, V <sub>cc-</sub> = Gnd, I <sub>ol</sub> = 5mA                         |                              |  |      | 1.5  | V     | 4, 5, 6    |      |         |
|                                |  | V <sub>cc+</sub> = 4.5V, V <sub>cc-</sub> = Gnd, I <sub>ol</sub> = 2uA                        |                              |  |      | 0.4  | V     | 4, 5, 6    |      |         |
| V <sub>oh</sub>                | Logical "1" Output Voltage                   | V <sub>cc+</sub> = 30V, V <sub>cc-</sub> = Gnd, I <sub>oh</sub> = -10mA                       |                              |  | 27   |      | V     | 4, 5, 6    |      |         |
|                                |  | V <sub>cc+</sub> = 4.5V, V <sub>cc-</sub> = Gnd, I <sub>oh</sub> = -10mA                      |                              |  | 2.4  |      | V     | 4, 5       |      |         |
|                                |  |   |                              |  | 2.3  |      | V     | 6          |      |         |

## Electrical Characteristics

## DC PARAMETERS (Continued)

| SYMBOL  | PARAMETER                    | CONDITIONS  | NOTES | PIN-NAME | MIN | MAX | UNIT | SUB-GROUPS |
|---------|------------------------------|---|-------|----------|-----|-----|------|------------|
| Avs+    | Voltage Gain                 | Vcc+ = 30V, Vcc- = Gnd,<br>1V ≤ Vo ≤ 26V, Rl = 10K Ohms | 1     |          | 50  |     | V/mV | 4          |
|         |                              |   | 1     |          | 25  |     | V/mV | 5, 6       |
|         |                              | Vcc+ = 30V, Vcc- = Gnd,<br>5V ≤ Vo ≤ 20V, Rl = 2K Ohms  | 1     |          | 50  |     | V/mV | 4          |
|         |                              |   | 1     |          | 25  |     | V/mV | 5, 6       |
| Avs     | Voltage Gain                 | Vcc+ = 5V, Vcc- = Gnd,<br>1V ≤ Vo ≤ 2.5V, Rl = 10K Ohms | 1     |          | 10  |     | V/mV | 4, 5, 6    |
|         |                              | Vcc+ = 5V, Vcc- = Gnd,<br>1V ≤ Vo ≤ 2.5V, Rl = 2K Ohms  | 1     |          | 10  |     | V/mV | 4, 5, 6    |
| +Vop    | Maximum Output Voltage Swing | Vcc+ = 30V, Vcc- = Gnd, Vo = +30V,<br>Rl = 10K Ohms     |       |          | 27  |     | V    | 4, 5, 6    |
|         |                              | Vcc+ = 30V, Vcc- = Gnd, Vo = +30V,<br>Rl = 2K Ohms      |       |          | 26  |     | V    | 4, 5, 6    |
| Vio(a)  | Tempco Screen                |   | 4     |          |     | 2.3 | mV   |            |
| Vio(b)  | Tempco Screen                |   | 4     |          |     | 2.5 | mV   |            |
| Iio(a)  | Tempco Screen                |   | 4     |          |     | 20  | nA   |            |
| Iio(b)  | Tempco Screen                |   | 4     |          |     | 16  | nA   |            |
| +Iib(a) | Tempco Screen                |   | 4     |          |     | 16  | nA   |            |
| +Iib(b) | Tempco Screen                |   | 4     |          |     | 10  | nA   |            |
| +Iib(c) | Tempco Screen                |   | 4     |          |     | 13  | nA   |            |
| -Iib(a) | Tempco Screen                |   | 4     |          |     | 16  | nA   |            |
| -Iib(b) | Tempco Screen                |   | 4     |          |     | 10  | nA   |            |
| -Iib(c) | Tempco Screen                |   | 4     |          |     | 13  | nA   |            |
| PSRR    | Tempco Screen                |   | 4     |          |     | 17  | uV   |            |

## Electrical Characteristics

### AC PARAMETERS

(The following conditions apply to all the following parameters, unless otherwise specified.)  
AC: +Vcc = 30V, -Vcc = 0V

| SYMBOL                                 | PARAMETER                     | CONDITIONS   | NOTES | PIN-NAME | MIN | MAX | UNIT   | SUB-GROUPS |
|--|-------------------------------|--|-------|----------|-----|-----|--------|------------|
| TR(tr)                                 | Transient Response: Rise Time | +Vcc = 30V, -Vcc = Gnd                                 |       |          |     | 1   | uS     | 7, 8A, 8B  |
| TR(os)                                 | Transient Response: Overshoot | +Vcc = 30V, -Vcc = Gnd                                 |       |          |     | 50  | %      | 7, 8A, 8B  |
| Sr+                                    | Slew Rate: Rise               | +Vcc = 30V, -Vcc = Gnd                                 |       |          | 0.1 |     | V/uS   | 7, 8A, 8B  |
| Sr-                                    | Slew Rate: Fall               | +Vcc = 30V, -Vcc = Gnd                                 |       |          | 0.1 |     | V/uS   | 7, 8A, 8B  |
| NI(BB)                                 | Noise Broadband               | +Vcc = 15V, -Vcc = -15V, BW = 10Hz to 5KHz             | 5     |          |     | 15  | uV/rms | 7          |
| NI(PC)                                 | Noise Popcorn                 | +Vcc = 15V, -Vcc = -15V, Rs = 20K Ohms                 | 2     |          |     | 50  | uV/pK  | 7          |
| Cs                                     | Channel Separation            | +Vcc = 30V, -Vcc = Gnd                                 | 5     |          | 80  |     | dB     | 7          |
|  |                               | +Vcc = 30V, -Vcc = Gnd, Vin = 1V and 16V, Rl = 2K Ohms | 5     |          | 80  |     | dB     | 7          |
|  |                               | Rl = 2K Ohms, Vin = 1V and 16V, A to B                 | 5     |          | 80  |     | dB     | 7          |
|  |                               | Rl = 2K Ohms, Vin = 1V and 16V, A to C                 | 5     |          | 80  |     | dB     | 7          |
|  |                               | Rl = 2K Ohms, Vin = 1V and 16V, A to D                 | 5     |          | 80  |     | dB     | 7          |
|  |                               | Rl = 2K Ohms, Vin = 1V and 16V, B to A                 | 5     |          | 80  |     | dB     | 7          |
|  |                               | Rl = 2K Ohms, Vin = 1V and 16V, B to C                 | 5     |          | 80  |     | dB     | 7          |
|  |                               | Rl = 2K Ohms, Vin = 1V and 16V, B to D                 | 5     |          | 80  |     | dB     | 7          |
|  |                               | Rl = 2K Ohms, Vin = 1V and 16V, C to A                 | 5     |          | 80  |     | dB     | 7          |
|  |                               | Rl = 2K Ohms, Vin = 1V and 16V, C to B                 | 5     |          | 80  |     | dB     | 7          |
|  |                               | Rl = 2K Ohms, Vin = 1V and 16V, C to D                 | 5     |          | 80  |     | dB     | 7          |
|  |                               | Rl = 2K Ohms, Vin = 1V and 16V, D to A                 | 5     |          | 80  |     | dB     | 7          |
|  |                               | Rl = 2K Ohms, Vin = 1V and 16V, D to B                 | 5     |          | 80  |     | dB     | 7          |
| Rl = 2K Ohms, Vin = 1V and 16V, D to C | 5                             |  | 80    |          | dB  | 7   |        |            |

## Electrical Characteristics

### DC PARAMETERS: DRIFT VALUES

(The following conditions apply to all the following parameters, unless otherwise specified.)  
 DC: "Delta calculations performed on JAN S and QMLV devices at group B, subgroup 5 only".

| SYMBOL | PARAMETER            | CONDITIONS                         | NOTES | PIN-NAME | MIN | MAX | UNIT | SUB-GROUPS |
|--------|----------------------|------------------------------------|-------|----------|-----|-----|------|------------|
| Vio    | Input Offset Voltage | Vcc+ = 30V, Vcc- = Gnd, Vcm = -15V |       |          | -1  | 1   | mV   | 1          |
| +Iib   | Input Bias Current   | Vcc+ = 30V, Vcc- = Gnd, Vcm = -15V |       |          | -15 | 15  | nA   | 1          |
| -Iib   | Input Bias Current   | Vcc+ = 30V, Vcc- = Gnd, Vcm = -15V |       |          | -15 | 15  | nA   | 1          |

Note 1: V/mV = K.

Note 2: Test on either A360, J273 AC or bench test.

Note 3: Calculated parameters.

Note 4: Temp. Co. DLOG readings will print and MNET transfer will occur only in Test Mode 2 = 1. Bin 5 is a potential Temp. Co. failure.

Note 5: Tested on LTX Channel Separation and Noise test tape.

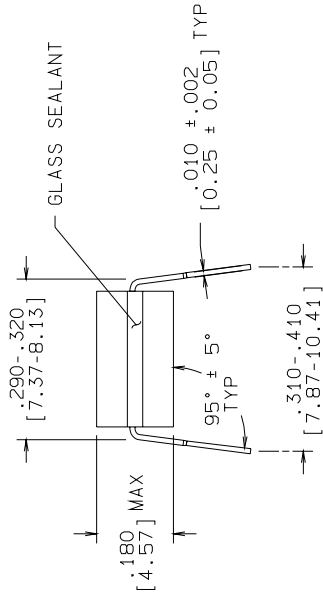
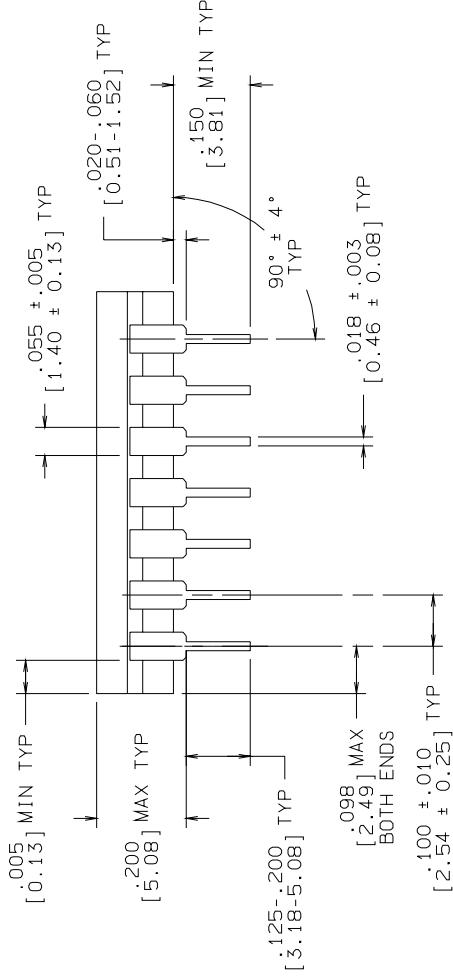
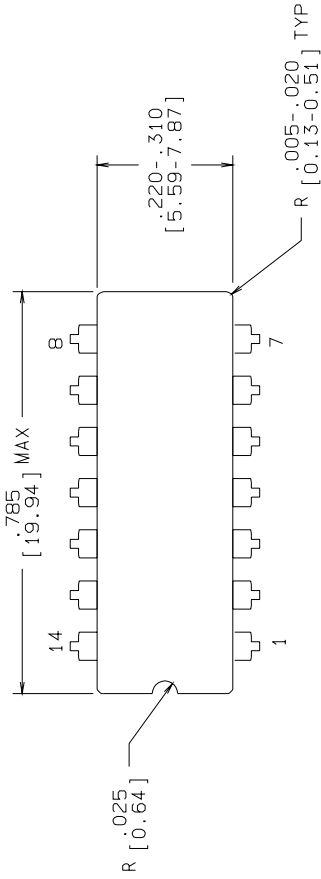


## Graphics and Diagrams

| GRAPHICS# | DESCRIPTION                         |
|-----------|-------------------------------------|
| 05275HRA4 | CERPACK (W), 14 LEAD (B/I CKT)      |
| 09173HRA2 | CERDIP (J), 14 LEAD (B/I CKT)       |
| J14ARH    | CERDIP (J), 14 LEAD (P/P DWG)       |
| P000254B  | CERAMIC SOIC (WG), 14 LEAD (PINOUT) |
| P000288A  | CERDIP (J), 14 LEAD (PINOUT)        |
| P000474A  | CERPACK (W), 14 LEAD (PIN OUT)      |
| W14BRN    | CERPACK (W), 14 LEAD (P/P DWG)      |
| WG14ARC   | CERAMIC SOIC (WG), 14LD (P/P DWG)   |

See attached graphics following this page.

| R E V I S I O N S |                                |        |          |
|-------------------|--------------------------------|--------|----------|
| LTR               | DESCRIPTION                    | E.C.N. | DATE     |
| H                 | REVISE PER CURRENT STD; REDRAW | 10001  | 09/15/93 |
|                   |                                |        | TL/      |



CONTROLLING DIMENSION: INCH

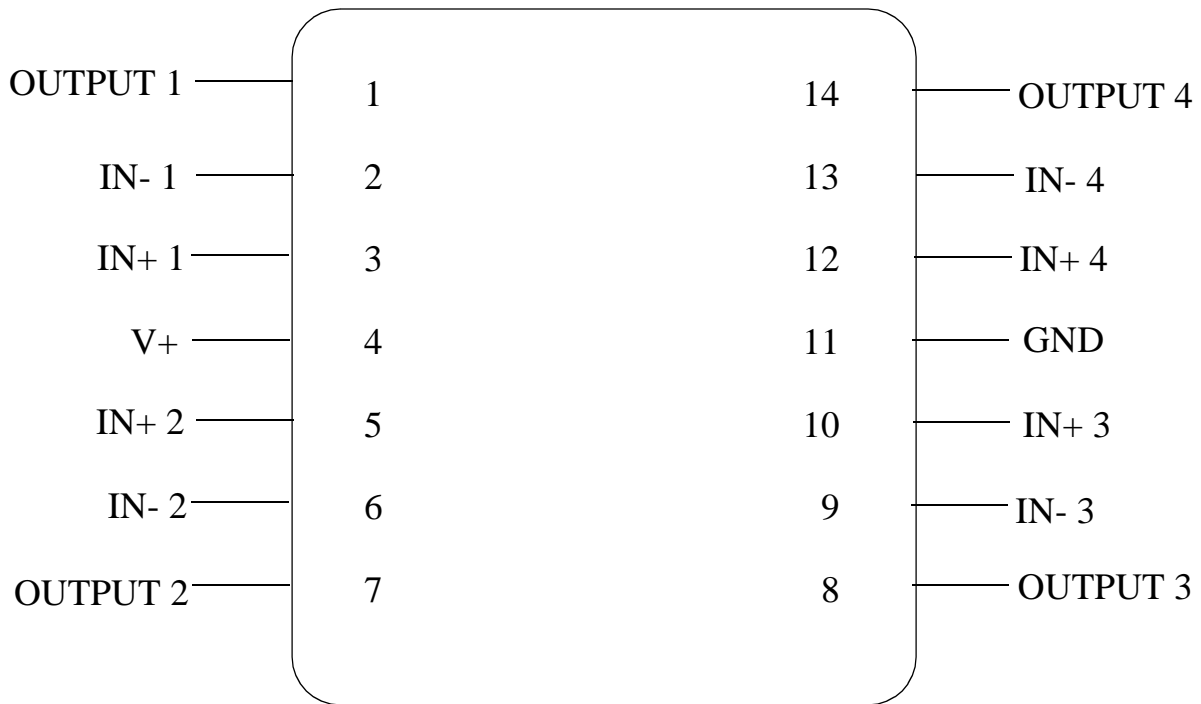
NOTES: UNLESS OTHERWISE SPECIFIED

1. LEAD FINISH TO BE 200 MICRONS / 5.08 MICROMETERS MINIMUM SOLDER MEASURED AT THE CREST OF THE MAJOR FLATS.
2. JEDEC REGISTRATION MO-036, VARIATION AB, DATED 04/1981.

MIL/AERO MIL-M-38510  
 CONFIGURATION CONTROL CONFIGURATION CONTROL

| APPROVALS                | DATE     | NATIONAL SEMICONDUCTOR CORPORATION                   |              |
|--------------------------|----------|--|--------------|
| DRAWN: <b>T. LEQUANG</b> | 09/15/93 | 2900 Semiconductor Drive, Santa Clara, CA 95052-8090 |              |
| DFTG. CHK.               |          |  |              |
| ENGR. CHK.               |          |  |              |
| APPROVAL                 |          |  |              |
| PROJECTION               |          | SCALE  | SIZE         |
|                          |          | N/A  | B            |
|                          |          | DRAWING NUMBER                                       | REV          |
|                          |          | MKT-J14A   | H            |
|                          |          | DO NOT SCALE DRAWING                                 | SHEET 1 OF 1 |

CERDIP (J),  
 14 LEAD,

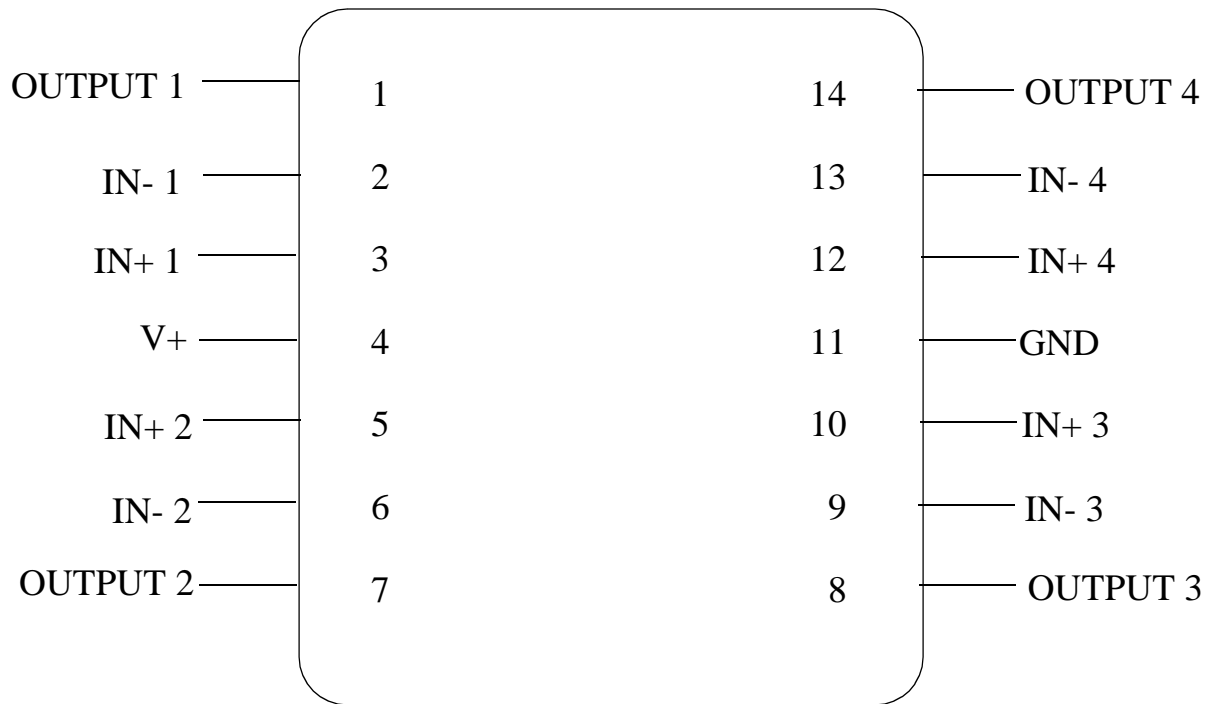


**LM124AWG, LM124WG**  
**14 - LEAD CERAMIC SOIC**  
**CONNECTION DIAGRAM**  
**TOP VIEW**  
**P000254B**



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MIL/AEROSPACE OPERATIONS  
 2900 SEMICONDUCTOR DRIVE  
 SANTA CLARA, CA 95050

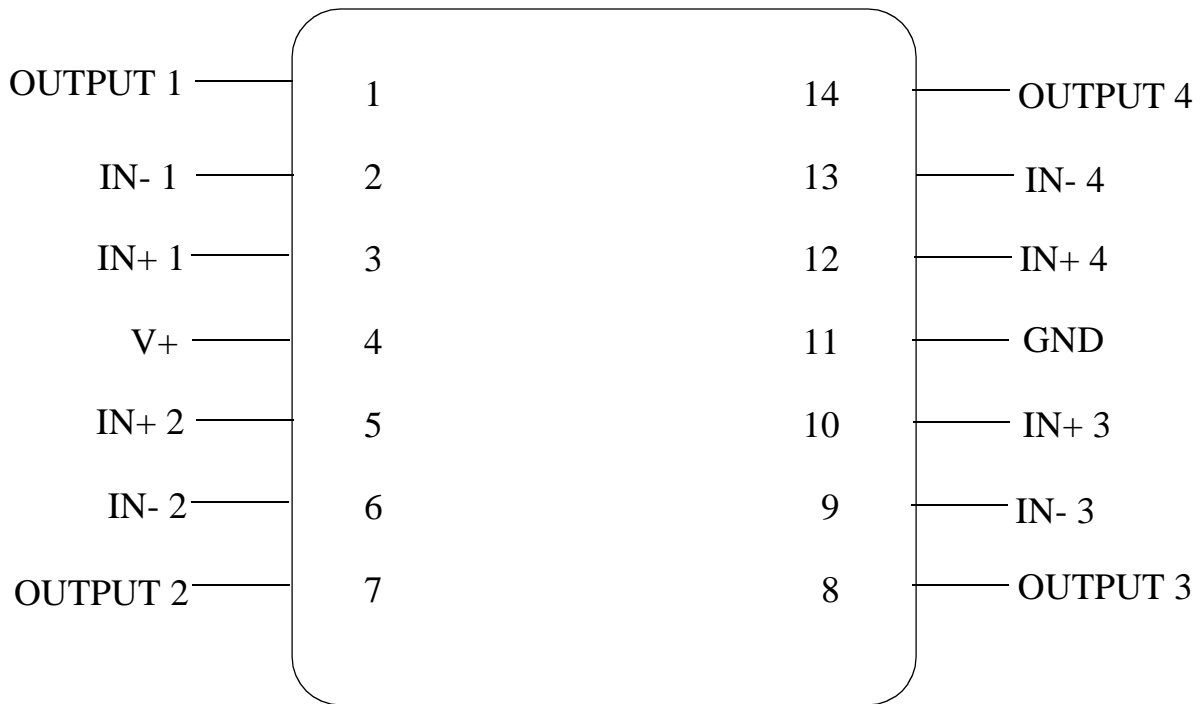


**LM124AJ, LM124J**  
**14 - LEAD DIP**  
**CONNECTION DIAGRAM**  
**TOP VIEW**  
**P000288A**



National Semiconductor™

MIL/AEROSPACE OPERATIONS  
 2900 SEMICONDUCTOR DRIVE  
 SANTA CLARA, CA 95050



**LM124AW, LM124W**  
**14 - LEAD CERAMIC CERPACK**  
**CONNECTION DIAGRAM**  
**TOP VIEW**  
**P000474A**

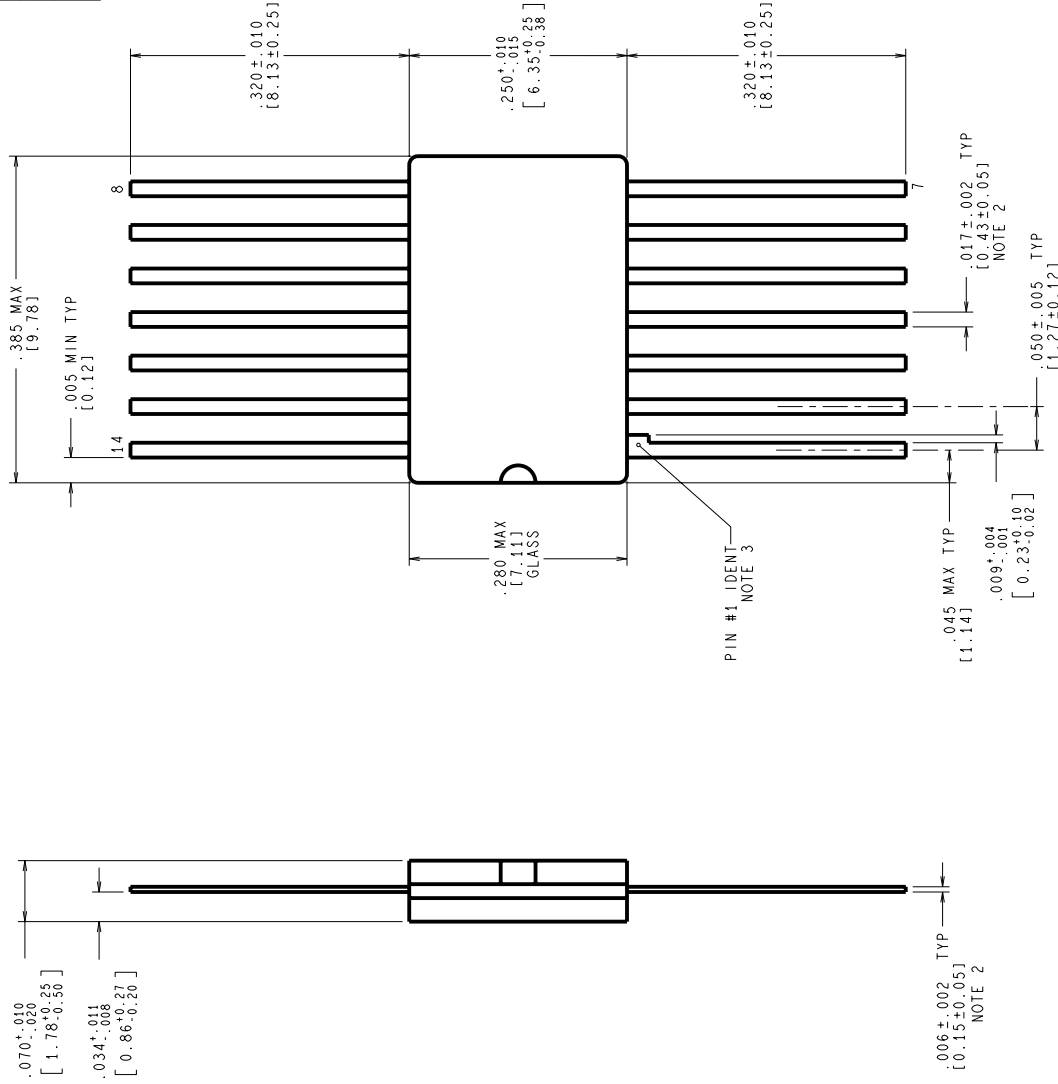


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 2900 SEMICONDUCTOR DRIVE  
 SANTA CLARA, CA 95050

REVISIONS

| LTR | DESCRIPTION  | E.C.N. | DATE     | BY/APP'D |
|-----|--|--------|----------|----------|
| L   | REVISE AND REDRAW PER NEW STANDARD.  | 10513  | 07/26/94 | DEG/AEP  |
| M   | .017±.002 WAS .017±.020.   | 10655  | 10/21/94 | DEG/CD   |
| N   | L/F THRS. .008±.002 WAS .005±.001; UPDATE NOTES 1 & 2; REMOVE NOTE 4; UPDATE MILAERO STAMP; DUAL DIM'S WERE INCHES ONLY. | 11005  | 06/08/95 | MS/      |



MIL-I-38535  
CONFIGURATION CONTROL

CONTROLLING DIMENSION IS INCH  
VALUES IN [ ] ARE MILLIMETERS

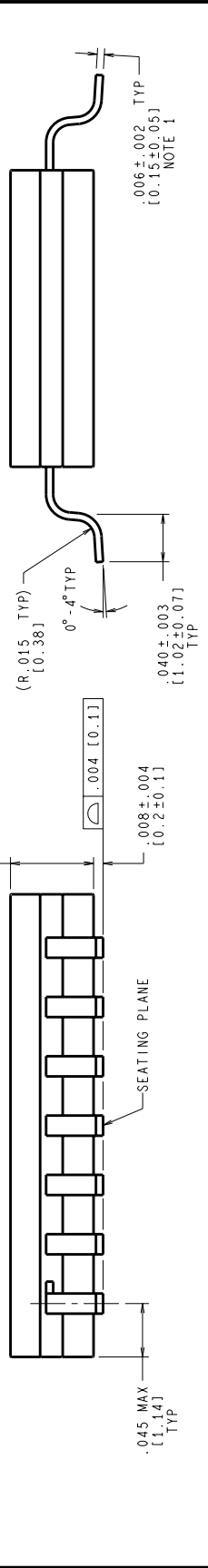
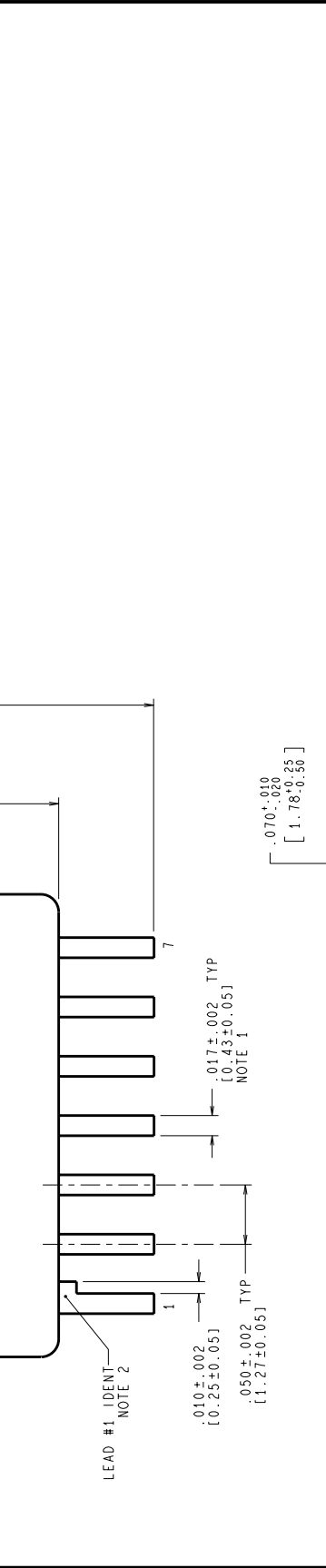
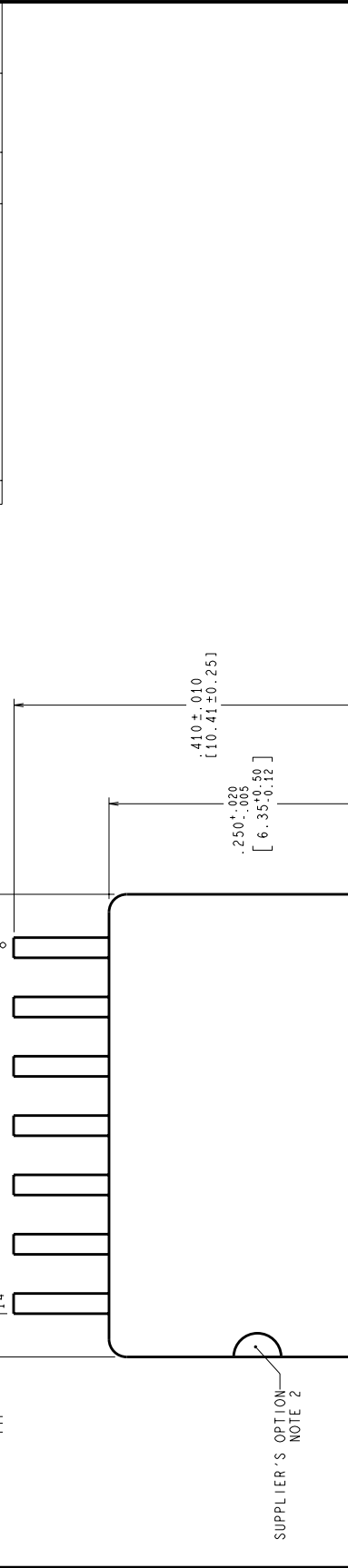
NOTES: UNLESS OTHERWISE SPECIFIED.

- LEAD FINISH: SOLDER DIPPED WITH Sn60 OR Sn63 SOLDER CONFORMING TO MIL-I-38535 TO A MINIMUM THICKNESS OF 200 MICRONS/ 5.08 MICROMETERS. SOLDER MAY BE APPLIED OVER LEAD BASIS METAL OR Sn PLATE.
- MAXIMUM LIMIT MAY BE INCREASED BY .003 INCHES/ 0.08 MILLIMETERS AFTER LEAD FINISH APPLIED.
- LEAD 1 IDENTIFICATION SHALL BE:
  - A NOTCH OR OTHER MARK WITHIN THIS AREA
  - A TAB ON LEAD 1, EITHER SIDE

| APPROVALS   | DATE     | SCALE | SIZE | DRAWING NUMBER | REV |
|---|----------|-------|------|----------------|-----|
| DRN: <i>D. E. Gredy</i>   | 07/26/94 | N/A   | C    | MKT-W14B       | N   |
| DATE: _____   |          |       |      |                |     |
| ENGR. CHK:  |          |       |      |                |     |
| PROJECTION  |          |       |      |                |     |
|   |          |       |      |                |     |
|   |          |       |      |                |     |
| <b>National Semiconductor</b><br>2800 Semiconductor Dr., Santa Clara, CA 95052-8090 |          |       |      |                |     |
| CERPACK, 14 LEAD  |          |       |      |                |     |
| DO NOT SCALE DRAWING  |          |       |      |                |     |
| SHEET 1 of 1  |          |       |      |                |     |

| REVISIONS |  |        |            |
|-----------|--|--------|------------|
| LTR       | DESCRIPTION  | E.C.N. | DATE       |
| A         | RELEASE TO DOCUMENT CONTROL  | 11375  | 02/29/1996 |
| B         | LD PITCH TOL WAS ±.005; CHANGE LD RADIUS TO REF DIM; REMOVE THE OTHER R.006±.002; DIM. .040±.003 WAS .037±.003 | 11442  | 04/19/1996 |
| C         | R. .015(0.38) WAS R. .006(0.15)  | 11839  | 10/08/1997 |

| APPROVALS          | DATE     | BY/APP'D |
|--------------------|----------|----------|
| DRN<br>MARTA SUCHY | 02/29/96 | MS/KH    |
| DATE CHK.          |          | MS/KH    |
| ENGR. CHK.         |          | TL/      |



CONTROLLING DIMENSION IS INCH  
VALUES IN | ARE MILLIMETERS

NOTES: UNLESS OTHERWISE SPECIFIED

- LEAD FINISH: SOLDER DIPPED WITH Sn60 OR Sn63 SOLDER CONFORMING TO MIL-PRF-38535 TO A MINIMUM THICKNESS OF 200 MICRONS/5.08 MICROMETERS. SOLDER MAY BE APPLIED OVER LEAD BASIS METAL OR Sn PLATE. MAXIMUM LIMIT MAY BE INCREASED BY .003 IN/ 0.08mm AFTER LEAD FINISH APPLIED.
- LEAD 1 IDENTIFICATION SHALL BE:
  - A NOTCH OR OTHER MARK WITHIN THIS AREA
  - A TAB ON LEAD 1, EITHER SIDE
- NO JEDEC REGISTRATION AS OF FEBRUARY 1996.

**MIL-PRF-38535  
CONFIGURATION CONTROL**

|                    |  |              |                      |
|--------------------|--|--------------|----------------------|
| APPROVALS          |  | DATE         | BY/APP'D             |
| DRN<br>MARTA SUCHY |  | 02/29/96     | MS/KH                |
| DATE CHK.          |  |              | MS/KH                |
| ENGR. CHK.         |  |              | TL/                  |
| PROJECTION         |  | SCALE        | DRAWING NUMBER       |
|                    |  | N/A          | C (SC)MKT-WG14A      |
|                    |  | DO NOT SCALE | DRAWING SHEET 1 of 1 |

*National Semiconductor*  
2800 Semiconductor Dr., Santa Clara, CA 95052-8000

**CERPACK,  
14 LEAD,  
GULL WING**

## Revision History

| Rev | ECN #    | Rel Date | Originator  | Changes   |
|-----|----------|----------|-------------|---|
| 1A0 | M0003654 | 03/28/02 | Rose Malone | Update MDS - MJLM124-X, Rev. 0B1 to Fully Released MDS, MJLM124-X, Rev. 1A0. Parameters Delta Vio/Delta T and Delta Iio/Delta T changed from $+25\text{ C} \leq \text{TA} \leq +125\text{ C}$ and $-55\text{ C} \leq \text{TA} \leq +25\text{ C}$ . Is Now, $+25\text{ C} \leq \text{TA} \leq +125\text{ C}$ , $+V_{cc} = 5\text{V}$ , $-V_{cc} = 0\text{V}$ , $V_{cm} = -1.4\text{V}$ and $-55\text{ C} \leq \text{TA} \leq +25\text{ C}$ , $+V_{cc} = 5\text{V}$ , $-V_{cc} = 0\text{V}$ , $V_{cm} = -1.4\text{V}$ . To clarify the Tempco test Conditions. |
| 1B1 | M0003979 | 03/28/02 | Rose Malone | Update MDS: MJLM124-X, Rev. 1A0 to JMLM124-X, Rev. 1B1. Added WG pkg to Main Table, Absolute Maximum Ratings Section and Graphics Section.  |